

## T2550H

## Snubberless™ high temperature 25 A Triacs

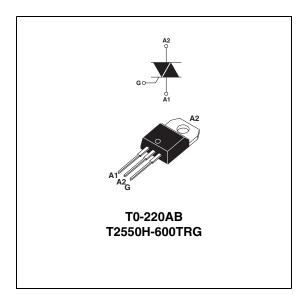
#### **Main features**

Symbol	Value	Unit
I <sub>T(RMS)</sub>	25	Α
V <sub>DRM</sub> /V <sub>RRM</sub>	600	V
I <sub>GT (Q₁)</sub>	50	mA

### **Description**

Specifically designed for use in high temperature environment (found in hot appliances such as cookers, ovens, hobs, electric heaters, coffee machines...), the new 25 A **T2550H** triacs provide an enhanced performance in terms of power loss and thermal dissipation. This allows for optimization of the heatsinking dimensioning, leading to space and cost effectivness when compared to electro-mechanical solutions.

Based on ST snubberless technology, they offer high commutation switching capabilities and high noise immunity levels. And, thanks to their clip assembly technique, they provide a superior performance in surge current handling.



#### Order code

Part Number	Marking
T2550H-600TRG	T2550H600T

Table 1. Absolute maximum ratings

Symbol	Parameter			Value	Unit
I <sub>T(RMS)</sub>	RMS on-state current (full sine wave) $T_c = 125$ °C		T <sub>c</sub> = 125°C	25	Α
1 -	Non repetitive surge peak on-state	F = 50 Hz	t = 20 ms	250	Α
I <sub>TSM</sub>	current (full cycle, T <sub>j</sub> initial = 25° C)	F = 60 Hz	t = 16.7 ms	260	A
l²t	I <sup>2</sup> t Value for fusing	$t_p = 10 \text{ ms}$		340	A <sup>2</sup> s
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \le 100 \text{ ns}$	F = 120 Hz	T <sub>j</sub> = 150°C	50	A/µs
V <sub>DSM</sub> /V <sub>RSM</sub>	Non repetitive surge peak off-state voltage	t <sub>p</sub> = 10 ms	T <sub>j</sub> = 25°C	700	V
I <sub>GM</sub>	Peak gate current	t <sub>p</sub> = 20 μs	T <sub>j</sub> = 150°C	4	Α
$P_{G(AV)}$	Average gate power dissipation		T <sub>j</sub> = 150°C	1	W
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range		- 40 to + 150 - 40 to + 150	°C	

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Characteristics T2550H

## 1 Characteristics

**Table 2. Electrical Characteristics** ( $T_j = 25^{\circ}C$ , unless otherwise specified)

Symbol	Test Conditions	Quadrant		Value	Unit
I <sub>GT</sub> <sup>(1)</sup>	V <sub>D</sub> = 12 V R <sub>I</sub> = 33 Ω	1 - 11 - 111	MAX.	50	mA
V <sub>GT</sub>	AD = 15 A UF = 22 75	1 - 11 - 111	MAX.	1.3	V
$V_{GD}$	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_j = 150^{\circ} \text{ C}$	1 - 11 - 111	MIN.	0.15	V
I <sub>H</sub> <sup>(2)</sup>	I <sub>T</sub> = 500 mA		MAX.	75	mA
ΙL	I <sub>G</sub> = 1.2 I <sub>GT</sub> I - II		MAX.	90	mA
dV/dt <sup>(2)</sup>	$V_D = 67\% V_{DRM}$ gate open $T_j = 150^{\circ} C$		MIN.	500	V/µs
(dl/dt)c <sup>(2)</sup>	Without snubber $T_j = 150^{\circ} \text{ C}$		MIN.	11.1	A/ms

<sup>1.</sup> minimum  $I_{GT}$  is guaranted at 10% of  $I_{GT}$  max.

Table 3. Static Characteristics

Symbol	Test Conditions			Value	Unit
V <sub>T</sub> <sup>(1)</sup>	$I_{TM} = 35 \text{ A}$ $t_p = 380 \text{ µs}$	T <sub>j</sub> = 25°C	MAX.	1.5	٧
V <sub>to</sub> (1)	V <sub>to</sub> <sup>(1)</sup> Threshold voltage		MAX.	0.80	٧
R <sub>d</sub> <sup>(1)</sup>	Dynamic resistance	T <sub>j</sub> = 150°C	MAX.	19	mΩ
I <sub>DRM</sub>	V V	T <sub>j</sub> = 25°C		5	μΑ
	$V_{DRM} = V_{RRM}$	T <sub>j</sub> = 150°C	MAX.	8.5	
I <sub>RRM</sub>	V <sub>DRM</sub> /V <sub>RRM</sub> = 400 V (at mains peak voltage)	T <sub>j</sub> = 150°C		5.5	mA

<sup>1.</sup> for both polarities of A2 referenced to A1.

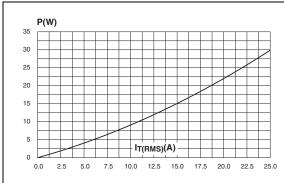
Table 4. Thermal resistance

Symbol	Parameter		Unit
R <sub>th(j-c)</sub>	Junction to case (AC)	0.8	°C/W

<sup>2.</sup> for both polarities of A2 referenced to A1.

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Figure 1. Maximum power dissipation versus Figure 2. RMS on-state current versus case temperature (full cycle)



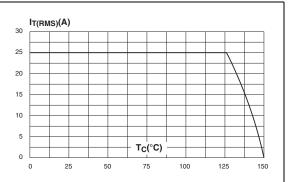
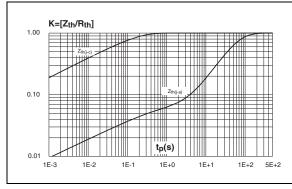


Figure 3. Relative variation of thermal impedance versus pulse duration

Figure 4. On-state characteristics (maximum values)



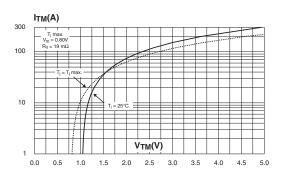
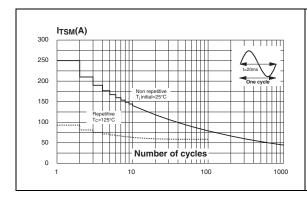
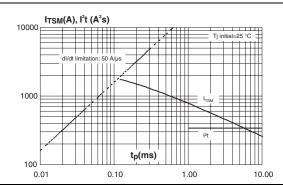


Figure 5. Surge peak on-state current versus Figure 6. number of cycles

Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10 \text{ ms}$  and corresponding value of  $l^2t$ 



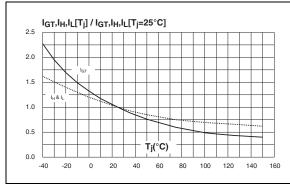


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Figure 7. Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)

Figure 8. Relative variation of critical rate of decrease of main current versus (dV/dt)c (typical values)



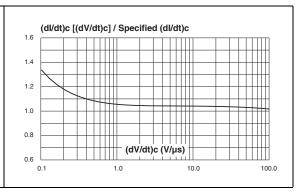
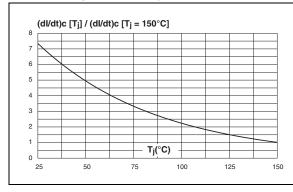


Figure 9. Relative variation of critical rate of decrease of main current versus junction temperature

Figure 10. Leakage current versus junction temperature for different values of blocking voltage (typical values)



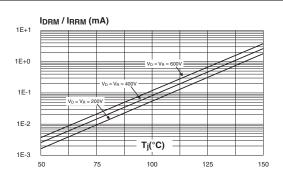
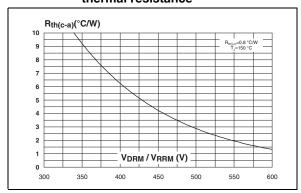
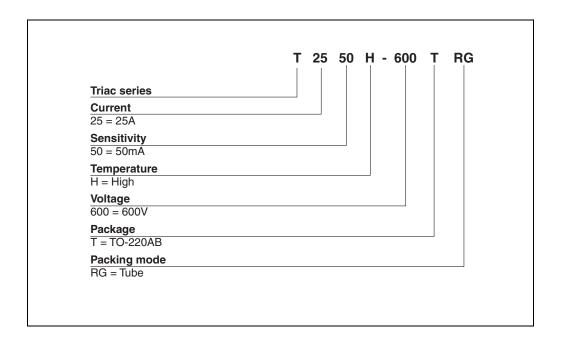


Figure 11. Acceptable repetitive peak off-state voltage versus case-ambient thermal resistance



## 2 Ordering information scheme

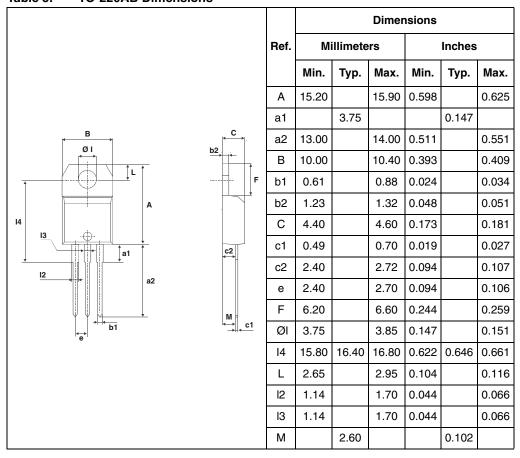


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Package information T2550H

### 3 Package information

Table 5. TO-220AB Dimensions



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

T2550H Ordering information

# 4 Ordering information

Ordering type Marking		Package	Weight	Base qty	Delivery mode	
	T2550H-600TRG	T2550H600T	TO-220AB	2.3 g	50	Tube

## 5 Revision history

Date	Revision Changes	
Apr-2002	5A	Last update.
13-Feb-2006	6	TO-220AB delivery mode changed from bulk to tube. ECOPACK statement added.
20-Jun-2006	7	Reformatted to current standards. Figures 6 and 11 replaced.

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